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**AMENDMENTS TO THE CLAIMS:**

Claim 1. (Currently amended) A light emitting apparatus, comprising:

a semiconductor light emitting element including a substrate, wherein light radiates from a light emission surface of the substrate of said light emitting element, the light emission surface being provided on the substrate opposite to an electrode forming surface of the substrate; and

a transparent structure mounted on the light emission surface of the substrate, wherein the transparent structure is optically connected with the light emission surface and has a light distribution characteristic based on a three-dimensional shape of the transparent structure,

wherein the transparent structure ~~comprise~~ comprises a side surface through which to allow the light to be discharged from the transparent structure.

Claim 2. (Cancelled).

Claim 3. (Original) The light emitting apparatus according to claim 1, wherein:

the transparent structure has a thickness of half that of the semiconductor light emitting element to twice the length of a shorter side of the semiconductor light emitting element.

Claim 4. (Original) The light emitting apparatus according to claim 1, wherein:

the transparent structure has a microscopic uneven surface to diffuse light.

Claim 5. (Original) The light emitting apparatus according to claim 1, wherein:

the transparent structure has a reflection layer formed on its surface.

Claim 6. (Previously presented) The light emitting apparatus according to claim 17, wherein:

one of the lead frames has a cup portion, and

the transparent structure is fixed on the cup portion through adhesive resin with light diffusion material mixed therein.

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**Claim 7.** (Previously presented) The light emitting apparatus according to claim 17, wherein:

the electrodes do not transmit light.

**Claim 8.** (Previously presented) A light emitting apparatus, comprising:  
a semiconductor light emitting element that includes a substrate and that radiates light from a light emission surface provided on the substrate of the semiconductor light emitting element opposite an electrode forming surface of the substrate;  
lead frames that are electrically connected to electrodes formed on the electrode forming surface through wires;  
a transparent structure that is mounted on the light emission surface of the substrate and optically connected with the light emission surface and has a light distribution characteristic based on a three-dimensional shape of the transparent structure; and  
light transmitting resin that seals the semiconductor light emitting element and the transparent structure, the light transmitting resin including a phosphor to wavelength-convert light emitted from the semiconductor light emitting element,  
wherein the transparent structure comprises a side surface through which to allow the light to be discharged from the transparent structure.

**Claim 9.** (Original) The light emitting apparatus according to claim 8, wherein:  
the light transmitting resin contains two or more kinds of phosphors.

**Claim 10.** (Previously presented) The light emitting apparatus according to claim 1, wherein the semiconductor light emitting element comprises the substrate, a buffer layer, an n-type semiconductor layer, a light-emitting layer, and a p-type semiconductor layer.

**Claim 11.** (Previously presented) The light emitting apparatus according to claim 1, wherein the semiconductor light emitting element comprises a gallium nitride system compound semiconductor.

**Claim 12.** (Previously presented) The light emitting apparatus according to claim 1,

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wherein the transparent structure comprises a light transmitting material comprising at least one of  $\text{SiO}_2$ ,  $\text{Al}_2\text{O}_3$ ,  $\text{SiC}$ ,  $\text{Si}_3\text{N}_4$ ,  $\text{AlN}$ ,  $\text{ZrO}_2$ , borosilicate glass, and alumino-silicate glass.

**Claim 13.** (Previously presented) The light emitting apparatus according to claim 1, wherein the substrate comprises sapphire.

**Claim 14.** (Previously presented) The light emitting apparatus according to claim 1, wherein the transparent structure is bonded to the substrate by an adhesive layer.

**Claim 15.** (Previously presented) The light emitting apparatus according to claim 14, wherein the adhesive layer comprises a transparent adhesive.

**Claim 16.** (Previously presented) A light emitting apparatus, comprising:

a semiconductor light emitting element that includes a substrate and that radiates light from a light emission surface provided on the substrate of the semiconductor light emitting element opposite to an electrode forming surface of the substrate;

lead frames that are electrically connected to electrodes formed on the electrode forming surface through wires;

a transparent structure that is mounted on the light emission surface of the substrate and optically connected with the light emission surface and has a light distribution characteristic based on a three-dimensional shape of the transparent structure; and

light transmitting resin that seals the semiconductor light emitting element and the transparent structure,

wherein the transparent structure comprises a side surface through which to allow the light to be discharged from the transparent structure.

**Claim 17.** (Previously presented) The light emitting apparatus according to claim 1, further comprising lead frames that are electrically connected to electrodes formed on the electrode forming surface through wires.

**Claim 18.** (Previously presented) The light emitting apparatus according to claim 1,

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further comprising light transmitting resin that seals the semiconductor light emitting element and the transparent structure.

**Claim 19.** (Previously presented) The light emitting apparatus according to claim 8, wherein the transparent structure is mounted on the light emission surface of the substrate by an adhesive layer.

**Claim 20.** (Previously presented) The light emitting apparatus according to claim 16, wherein the transparent structure is mounted on the light emission surface of the substrate by an adhesive layer.

**Claim 21.** (Previously presented) The light emitting apparatus according to claim 1, wherein the side surface comprises an inclined plane.

**Claim 22.** (Previously presented) The light emitting apparatus according to claim 8, wherein the side surface comprises an inclined plane.

**Claim 23.** (Previously presented) The light emitting apparatus according to claim 16, wherein the side surface comprises an inclined plane.